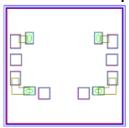
# AMT1709 2 - 18GHz SPST Switch Chip



#### **Key Features:**

• Frequency range: 2 – 18GHz

Insertion loss: 1.4dBIsolation: 70dB

Switch ON input/output standing wave : 1.2/1.2
Switch OFF input/output standing wave : 1.3/1.3

Switching time : 49nsControl method : 0/-5V

• Chip dimensions: 1.05mm x 1.05mm x 0.1mm

• Applications: wireless communication, transceiver module, radio telecommunication etc.

#### **Description:**

AMT1709 is a high performance FET SPST switch chip, it is designed by Gallium Arsenide (GaAs) pHEMT process. This chip is designed with ground through metal vias on the back technology. All chip products p are 100% RF tested. The chip uses 0V, -5V supply, TTL level control, typical insertion loss is 1.4dB, isolation is 70dB, input/output standing wave is 1.2.

## **Absolute Maximum Ratings (Ta = 25°C)**

| Symbol | Parameter             | Value        | Remark                         |
|--------|-----------------------|--------------|--------------------------------|
| V1, 2  | Control voltage       | 0.6V/-8V     |                                |
| Pin    | Input Power           | 30dBm        |                                |
| Tm     | Sintering Temperature | 310°C        | 30s, N <sub>2</sub> protection |
| Tstg   | Storage Temperature   | -65 ~ +150°C |                                |

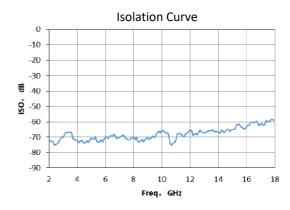
[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

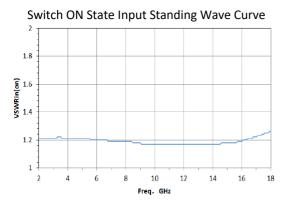
### **Electrical Characteristics (Ta = 25°C)**

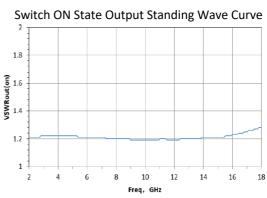
| Symbol       | Parameter                      | <b>Test Conditions</b> | Value |         | Unit |    |
|--------------|--------------------------------|------------------------|-------|---------|------|----|
|              |                                |                        | Min   | Typical | Max  |    |
| VSWRin (On)  | ON state input standing wave   |                        | -     | 1.2     | 1.3  | •  |
| VSWRout(On)  | ON state output standing wave  |                        | -     | 1.2     | 1.3  | -  |
| VSWRin(Off)  | OFF state input standing wave  | F : 2 ~ 18GHz          | -     | 1.3     | 1.5  | -  |
| VSWRout(Off) | OFF state output standing wave |                        | -     | 1.3     | 1.5  | -  |
| IL           | Insertion Loss                 |                        | -     | 1.4     | 1.6  | dB |
| ISO          | Isolation                      |                        | 53    | 70      | -    | dB |

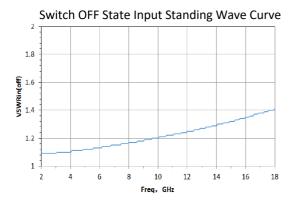
# **Typical Performance**

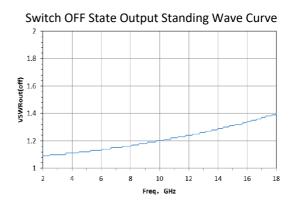




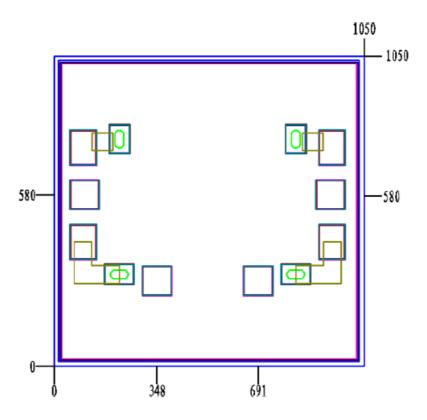




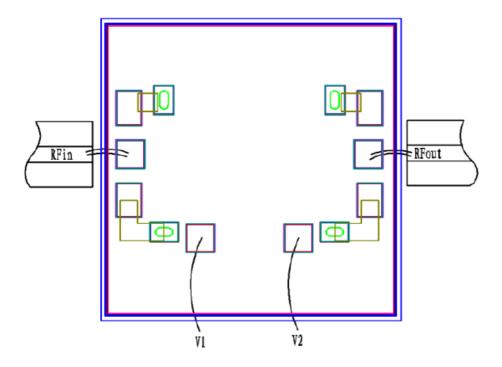




# Chip Dimensions (Unit: $\mu$ m)



# **Chip Layout Diagram**



#### **Pad Definition**

| No. | Symbol | Function Description   | Dimension   |
|-----|--------|--|-------------|
| 1   | RFin   | RF signal input port, external connect to $50\Omega$ system, no DC blocking capacitor  | 100μm*100μm |
| 2   | RFout  | RF signal output port, external connect to $50\Omega$ system, no DC blocking capacitor | 100μm*100μm |
| 3   | V1     | Supply voltage control port, see Truth Table for control logic                         | 100μm*100μm |
| 4   | V2     | Supply voltage control port, see Truth Table for control logic                         | 100μm*100μm |

#### **Truth Table**

| V1  | V2  | RFin – RFout |
|-----|-----|--------------|
| 0V  | -5V | ON           |
| -5V | 0V  | OFF          |

Please see Appendix A for details.